

DIFFERENTIAL VARIABLE GAIN AMPLIFIER FOR ADSL LINE INTERFACE

■ LOW NOISE: 4.7nV/√Hz

■ LOW DISTORTION

■ HIGH SLEW RATE: 90V/µs

■ WIDE BANDWIDTH: **52MHz** @ -3dB &

18dB gain

■ GAIN PROGRAMMABLE from -9dB to +30dB

with 3dB STEPS

POWER DOWN FUNCTION

DESCRIPTION

This TS636 is particularly intended for applications such as preamplification in telecommunication systems using multiple carriers. It has been minly designed to fit with ADSL chip-sets such as ASCOT ADSL chip-set for CPE.

The TS636 is a differential digitally controlled variable gain amplifier featuring a high slew rate of $90V/\mu s$, a large bandwidth, a very low distortion and a very low current and voltage noise.

The gain can be set from -9dB to +30dB through a 4bit digital word, with 3dB steps.

The gain monotonicity is guaranteed by design.

The TS636 comes in SO-14 plastic packages.

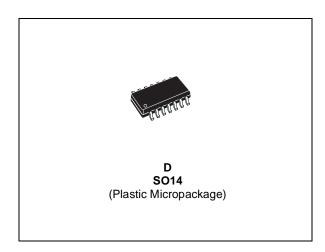
APPLICATION

Preamplifier with automatic gain control for Asymmetric Digital Subscriber Line (ADSL).

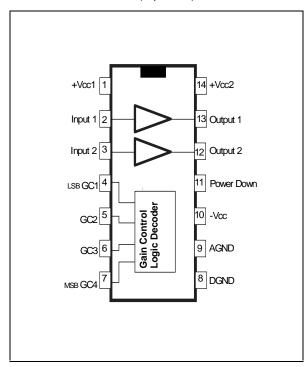
ORDER CODE

Part Number	art Number Temperature Range -	Package	
Part Number	remperature Kange	D	
TS636I	-40, +85°C	•	

 ${\bf D}$ = Small Outline Package (SO) - also available in Tape & Reel (DT)



PIN CONNECTIONS (top view)



January 2001 1/9

ABSOLUTE MAXIMUM RATINGS

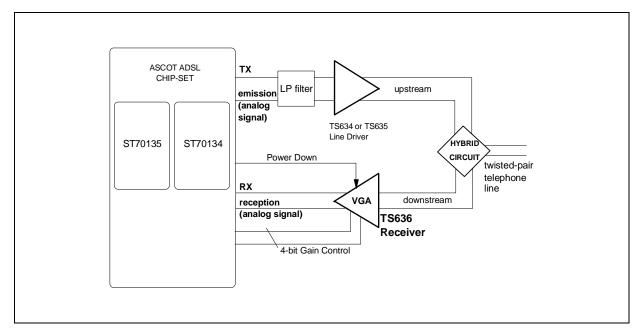
Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage ¹⁾	14	V
V _i	Input Voltage ²⁾	0 to 14	V
T _{oper}	Operating Free Air Temperature Range TS636ID	-40 to + 85	°C
T _{std}	Storage Temperature	-65 to +150	°C
T _j	Maximum Junction Temperature	150	°C
R _{thjc}	Thermal Resistance Junction to Case	22	°C/W
R _{thja}	Thermal Resistance Junction to Ambiante Area	125	°C/W
	Output Short Circuit Duration	Infinite	

All voltages values are with respect to network terminal.

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	5 to 12	V
V_{icm}	Common Mode Input Voltage	V _{CC} /2	V

APPLICATION: ADSL LINE INTERFACE



^{2.} The magnitude of input and output voltages must never exceed $\rm V_{CC}$ +0.3V.

ELECTRICAL CHARACTERISTICS. $V_{\text{CC}} = \pm 6 \text{Volts}, T_{\text{amb}} = 25 ^{\circ}\text{C}$ (unless otherwise specified).

Symbol	Parameter	Test Condition	Min.	Тур.	Max	Unit	
DC PERI	FORMANCE						
l _{ib}	Input Bias Current (AGND pin)			8		μΑ	
I _{CC}	Total Supply Current	No load, V _{out} = 0		28		mA	
	Differential Input Offset Voltage	$V_{in} = 0, A_{V} = 30dB$			6	mV	
SVR	Supply Voltage Rejection Ratio	$A_V = 0$ dB	50	80		dB	
	DOWN MODE						
I _{ccpdw}	Power Down Total Consumption	Power Down Mode			150	μΑ	
Z _{out}	Power Down Output Impedance		100kΩ	150kΩ//5pF		i i	
	FORMANCE						
Z_{in}	Input Impedance			100kΩ//5pF			
V _{OH}	High Level Output Voltage R _L connected to GND	$R_L = 500\Omega$	4	4.5		V	
V _{OL}	Low Level Output Voltage R _L connected to GND	$R_L = 500\Omega$		-4.5	-4	V	
۸	Voltage Gain	F= 1MHz	-9		20	٩D	
A_V	Gain monotonicity guaranteed by	-	-9		30	dB	
P_{AV}	Precision of the Voltage Gain	F= 1MHz	-1.4		1.4	dB	
A _{vstep}	Step Value	F= 1MHz	2.4	3	3.6	dB	
A_{vmis}	Gain Mismatch between Both Channels	F= 1MHz			1	dB	
D	Bandwidth @ -3dB	$A_V = -9dB$	45	100		MHz	
B_w	$R_L = 500\Omega, C_L = 15pF$	$A_V = +30dB$	9	17		MHz	
R_{bw}	Bandwidth Roll-off	$A_V = +30$ dB, $F = 1$ MHz		0.08		dB	
ı	Bandwidth @ -3dB	Source	17	28		mA	
I _o	$R_{L} = 500\Omega, C_{L} = 15pF$	Sink	17	22		ША	
SR	Slew Rate (gain independent)	V _o = 2Vpeak	40	90		V/μs	
NOISE A	ND DISTORTION						
in	Equivalent Input Noise Current	F = 100kHz		1.6		pA/√Hz	
en	Equivalent Input Noise Voltage	$F = 100kHz$ $A_V = 30dB$		4.7		nV/√Hz	
		1Vpeak, F = 150kHz, $A_V = +30dB$, $R_L = 500\Omega//15pF$					
THD30	Harmonic Distorsion	H2		-70		dBc	
111030	Tamonic Distorsion	H3		-93		ubc	
		H4		-98			
		H5		-99		ļ	
	Third Order Intermodulation	$V_{out} = 1Vpeak, A_V = +30dB$ $R_L = 500\Omega//15pF$					
IM3_1	Product	@ 80kHz		-77		dBc	
11413_1	F1 = 180kHz, F2 = 280kHz	@ 380kHz		-85			
		@640kHz		-86			
		@740kHz		-87			
	Third Order Intermodulation	$V_{out} = 1Vpeak, A_V = +30dB$ $R_L = 500\Omega//15pF$					
IM3_2	Product	@ 60kHz	_	-77		dBc	
IIVIO_Z	F1 = 70kHz, F2 = 80kHz	@ 90kHz		-79		ubc	
	– 10M 12, 1 2 – 00M 12	@220kHz		-83			
		@230kHz		-84			

DIGITAL INPUTS

Pin	Parameter	Min.	Тур.	Max.	Unit	
GC1, GC2, GC3	Low Level		0	0.8	V	
and GC4	High Level	2	3.3		V	
Power Down	Thershold Voltage for Power Down Mode (high level active)		0	0.8	V	
1 ower bown		2	3.3		V	

SIMPLIFIED SCHEMATIC

The TS636 consists of two independent channels.

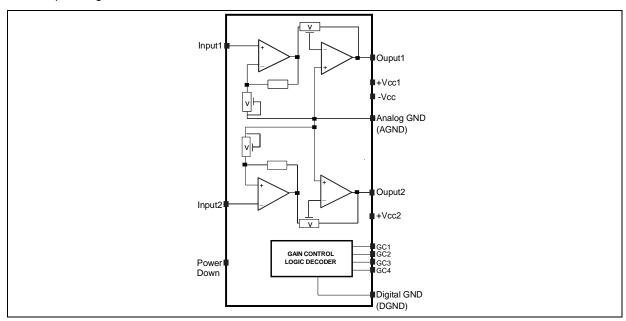
Each channel has two stages. The first is a very low noise digitally controlled variable gain amplifier (range 0 to 18dB).

The TS636 features a high input impedance and a low noise current. To minimize the overall noise figure, the source impedance must be less than $3k\Omega$.

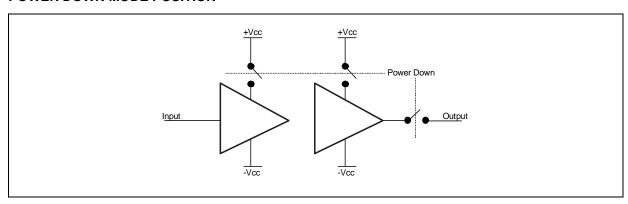
This value gives an equal contribution of voltage and current noises.

The second stage is a gain/attenuation stage (+12dB to -9dB) featuring a low output impedance.

This output stage can drive loads as low as 500Ω .



POWER DOWN MODE POSITION



4/9

BANDWIDTH

The small signal bandwidth is almost constant for gains between +18dB to 0dB and is in the order of 52MHz to 70MHz respectively. For 30dB gain the bandwidth is around 18MHz.

The power bandwidth is typically equal to 30MHz for 2V peak to peak signals.

MAXIMUM INPUT LEVEL

The input level must not exceed the following values:

negative peak value: must be greater than $-V_{CC} + 1.5V$

positive peak value: must be less than +V_{CC} - 1.5V

For example, if a ±6V power supply is used, the input signal can swing between -4.5V and +4.5V.

These values are due to common mode input range limitations of the input stage of the first amplifier.

Some other limitations may occur, due to the slew rate of the first operational amplifier (typically in the order of $300V/\mu s$). This means that the maximum input signal decreases at high frequency.

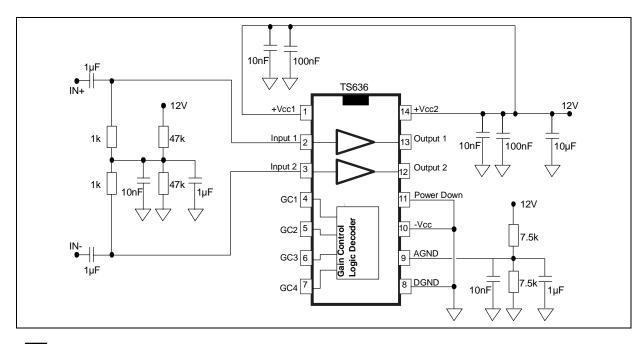
SINGLE SUPPLY OPERATION

The incoming signal is AC coupled to the inputs.

The TS636 can be used either with a dual or a single supply. If a single supply is used, the inputs are biased to the mid supply voltage ($+V_{CC/2}$). This bias network must be carefully designed, in order to reject any noise present on the supply rail.

The AGND pin (9) must be connected to $+V_{CC/2}$. The bias current of the second stage (inverting structure) is $8\mu A$ for both amplifiers. A resistor divider structure can be used. Two resistances should be chosen by considering $8\mu A$ as the 1% of the total current through these resistances. For a single +12V supply voltage, two resistances of $7.5k\Omega$ can be used. The differential input consists of a high pass circuit, formed by the $1\mu F$ capacitor and a $1k\Omega$ resistance and gives a break frequency of 160Hz.

SINGLE +12V SUPPLY OF THE TS636



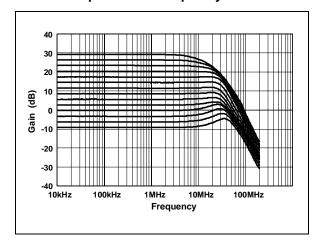
GAIN CONTROL

The gain and the power down mode is programmed with a 4 bit digital word :

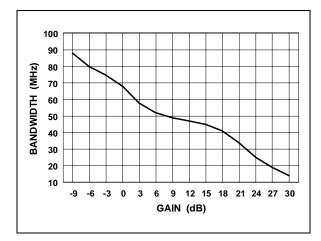
Digital Control GC4GC1 MSB LSB	Total Gain (dB)	First Stage Gain (dB)	Second Stage Gain (dB)	Maximum Input Level	Bandwidth Small Signal	Eq. Input Noise (nV/√Hz)
\$0000	-9	0	-9	2.8Vrms	110MHZ	29
\$0001	-6	0	-6	2.8Vrms	100MHz	26
\$0010	-3	0	-3	2.8Vrms	85MHz	23
\$0011	0	0	0	2.8Vrms	69MHz	22
\$0100	3	3	0	2Vrms	63MHz	16
\$0101	6	6	0	1.4Vrms	58MHz	12
\$0110	9	9	0	1Vrms	56MHz	9
\$0111	12	12	0	0.7Vrms	55MHz	7
\$1000	15	15	0	0.5Vrms	54MHz	6
\$1001	18	18	0	0.35Vrms	52MHz	4.8
\$1010	21	21	3	0.25Vrms	42MHz	4.7
\$1011	24	24	6	175mVrms	30MHz	4.7
\$1100	27	27	9	125mVrms	24MHz	4.6
\$1101	30	30	12	88mVrms	18MHz	4.6
\$1110	30	30	12	88mVrms	18MHz	4.6
\$1111	30	30	12	88mVrms	18MHz	4.6

The gain is the same for both channels. The digital inputs are CMOS compatible. The supply voltage of the logic decoder used to transcode the digital word can be either 3.3V or 5V or V_{CC} .

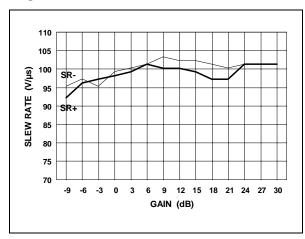
Closed Loop Gain vs. Frequency



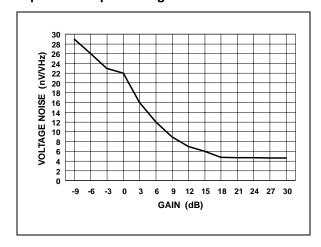
Bandwidth vs. Gain



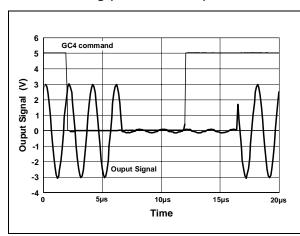
Negative & Positive Slew Rate vs. Gain



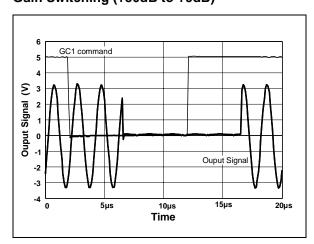
Equivalent Input Voltage Noise vs. Gain



Gain Switching (+15dB to -9dB)



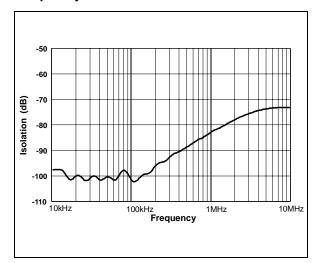
Gain Switching (+30dB to +9dB)



measurement conditions: Vcc= \pm 6V, Rload=500 Ω , Tamb=25°C

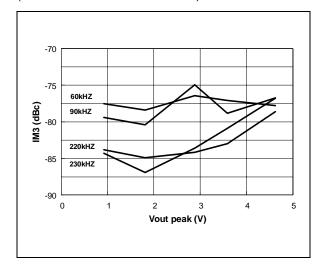


Output/Input Isolation in Power Down Mode vs. Frequency



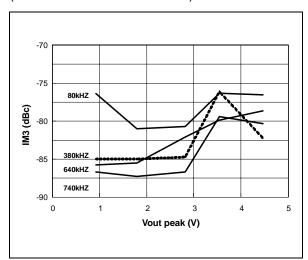
3rd Order Intermodulation

(2 tones: 180kHz and 280kHz)



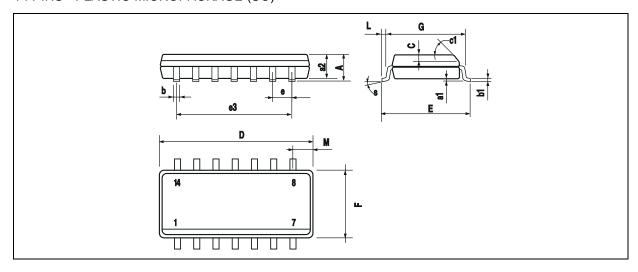
3rd Order Intermodulation

(2 tones: 180kHz and 280kHz)



PACKAGE MECHANICAL DATA

14 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.020	
c1			45°	(typ.)		
D (1)	8.55		8.75	0.336		0.344
Е	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		7.62			0.300	
F (1)	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
М			0.68			0.027
S	8° (max.)					

Note: (1) D and F do not include mold flash or protrusions - Mold flash or protrusions shall not exceed 0.15mm (.066 inc) ONLY FOR DATA BOOK.

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